

**COMBINED DECLARATION FOR PATENT APPLICATION AND POWER OF ATTORNEY**  
 (Includes Reference to PCT International Applications)

 ATTORNEY'S  
 DOCKET NUMBER  
 P02,0022

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.  
 I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled:

**"METHOD FOR PRODUCING INTEGRATED SEMICONDUCTOR COMPONENTS"**

the specification of which (check only one item below):

- ☐ is attached hereto.
- ☐ was filed as United States application  
 Serial No. \_\_\_\_\_  
 on \_\_\_\_\_,  
 and was amended  
 on \_\_\_\_\_ (if applicable).
- ☒ was filed as PCT international application  
 Number PCT/DE99/02339  
 on 29 July 1999,  
 and was amended under PCT Article 19  
 on \_\_\_\_\_ (if applicable).

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

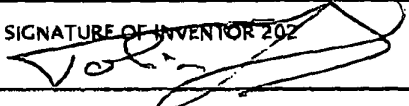
I acknowledge the duty to disclose information which is material to the examination of this application in accordance with Title 37, Code of Federal Regulations, §1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, §119 of any foreign application(s) for patent or inventor's certificate or of any PCT international application(s) designating at least one country other than the United States of America listed below and have also identified below any foreign application(s) for patent or inventor's certificate or any PCT international application(s) designating at least one country other than the United States of America filed by me on the same subject matter having a filing date before that of the application(s) of which priority is claimed:

**PRIOR FOREIGN/PCT APPLICATION(S) AND ANY PRIORITY CLAIMS UNDER 35 U.S.C. 119:**

COUNTRY (if PCT indicate "PCT")	APPLICATION NUMBER	DATE OF FILING (day, month, year)	PRIORITY CLAIMED UNDER 35 USC 119
PCT	PCT/DE99/02339	29 July 1999	<input checked="" type="checkbox"/> YES <input type="checkbox"/> NO
			<input type="checkbox"/> YES <input type="checkbox"/> NO
			<input type="checkbox"/> YES <input type="checkbox"/> NO
			<input type="checkbox"/> YES <input type="checkbox"/> NO

are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR 201	SIGNATURE OF INVENTOR 202 	SIGNATURE OF INVENTOR 203
DATE	DATE 22.1.2002	DATE

20020101 20020101



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			<input type="checkbox"/> YES <input type="checkbox"/> NO
			<input type="checkbox"/> YES <input type="checkbox"/> NO

**Combined Declaration For Patent Application and Power of Attorney  
(Continued)**

ATTORNEY'S DOCKET NO.  
P02.0022

I hereby claim the benefit under Title 35, United States Code, §120 of any United States application(s) or PCT international application(s) designating the United States of America that is/are listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in that/those prior application(s) in the manner provided by the first paragraph of Title 35, United States Code, §112, I acknowledge the duty to disclose material information as defined in Title 37, Code of Federal Regulations, §1.56 which occurred between the filing date of the prior application(s) and the national or PCT international filing date of this application.

**PRIOR U.S. APPLICATIONS OR PCT INTERNATIONAL APPLICATIONS DESIGNATING THE U.S. FOR BENEFIT UNDER 35 U.S.C. 120:**

U.S. APPLICATIONS			STATUS (Check one)		
U.S. APPLICATION NUMBER	U.S. FILING DATE		PATENTED	PENDING	ABANDONED
PCT APPLICATIONS DESIGNATING THE U.S.					
PCT APPLICATION NO	PCT FILING DATE	U.S. SERIAL NUMBERS ASSIGNED (if any)			

**POWER OF ATTORNEY:** As a named inventor, I hereby appoint all Attorneys identified by United States Patent & Trademark Office Customer Number 26574, who are all members of the Firm Schiiff Hardin & Walte.

**Send Correspondence to:**

**SCHIFF HARDIN & WAITE**  
Patent Department  
6600 Sears Tower, Chicago, Illinois 60606-6473

Direct Telephone Calls to:  
(312) 258-5781

	FULL NAME OF INVENTOR	FAMILY NAME	FIRST GIVEN NAME	SECOND GIVEN NAME
201	1-00	Heineck	Lars-Peter	
	RESIDENCE & CITIZENSHIP	CITY 06217 Merseburg	STATE OR FOREIGN COUNTRY Germany	COUNTRY OF CITIZENSHIP Germany DEX
	POST OFFICE ADDRESS	POST OFFICE ADDRESS Friedrich-Wähler-Str. 2	CITY 06217 Merseburg	STATE & ZIP CODE/COUNTRY Germany
202	2-00	Jacobs	Tobias	
	RESIDENCE & CITIZENSHIP	CITY 75012 Paris	STATE OR FOREIGN COUNTRY France	COUNTRY OF CITIZENSHIP Germany DEX
	POST OFFICE ADDRESS	POST OFFICE ADDRESS 8, Rue Parrot	CITY 75012 Paris	STATE & ZIP CODE/COUNTRY France
203	3-00	Winnerl	Josef	
	RESIDENCE & CITIZENSHIP	CITY 81929 Munich	STATE OR FOREIGN COUNTRY Germany	COUNTRY OF CITIZENSHIP Germany DEX
	POST OFFICE ADDRESS	POST OFFICE ADDRESS Stefan-George-Ring 47	CITY 81929 Munich	STATE & ZIP CODE/COUNTRY Germany

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SIGNATURE OF INVENTOR 201	SIGNATURE OF INVENTOR 202	SIGNATURE OF INVENTOR 203 <i>Jens-J. Lohme</i>
DATE	DATE	DATE 21.1.02

2002 JAN 25 14:00

are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

SIGNATURE OF INVENTOR 201 	SIGNATURE OF INVENTOR 202	SIGNATURE OF INVENTOR 203
DATE 24-01-2002	DATE	DATE

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